

# 2SA1381/KSA1381

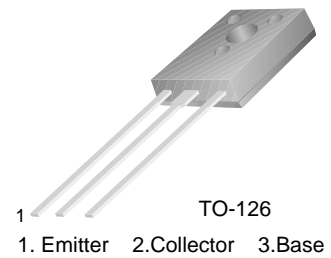
## PNP Epitaxial Silicon Transistor

### Applications

- Audio, Voltage Amplifier and Current Source
- CRT Display, Video Output
- General Purpose Amplifier

### Features

- High Voltage :  $V_{CEO} = -300V$
- Low Reverse Transfer Capacitance :  $C_{re} = 2.3pF$  at  $V_{CB} = -30V$
- Excellent Gain Linearity for low THD
- High Frequency: 150MHz
- Full thermal and electrical Spice models are available
- Complement to 2SC3503/KSC3503



### Absolute Maximum Ratings\* $T_a = 25^\circ C$ unless otherwise noted

| Symbol         | Parameter   | Ratings     | Units      |
|----------------|---|-------------|------------|
| $BV_{CBO}$     | Collector-Base Voltage  | -300        | V          |
| $BV_{CEO}$     | Collector-Emitter Voltage                                       | -300        | V          |
| $BV_{EBO}$     | Emitter-Base Voltage  | -5          | V          |
| $I_C$          | Collector Current(DC)   | -100        | mA         |
| $I_{CP}$       | Collector Current(Pulse)  | -200        | mA         |
| $P_C$          | Total Device Dissipation, $T_C=25^\circ C$<br>$T_C=125^\circ C$ | 7<br>1.2    | W<br>W     |
| $T_J, T_{STG}$ | Junction and Storage Temperature                                | - 55 ~ +150 | $^\circ C$ |

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics\* $T_a=25^\circ C$ unless otherwise noted

| Symbol          | Parameter                            | Max. | Units        |
|-----------------|--------------------------------------|------|--------------|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case | 17.8 | $^\circ C/W$ |

\* Device mounted on minimum pad size

### $h_{FE}$ Classification

| Classification | C       | D        | E         | F         |
|----------------|---------|----------|-----------|-----------|
| $h_{FE}$       | 40 ~ 80 | 60 ~ 120 | 100 ~ 200 | 160 ~ 320 |

**Electrical Characteristics\***  $T_a=25^\circ\text{C}$  unless otherwise noted

| Symbol        | Parameter                            | Test Condition                             | Min.  | Typ. | Max.  | Units         |
|---------------|--------------------------------------|--|-------|------|-------|---------------|
| $BV_{CBO}$    | Collector-Base Breakdown Voltage     | $I_C = -10\mu\text{A}, I_E = 0$            | - 300 |      |       | V             |
| $BV_{CEO}$    | Collector- Emitter Breakdown Voltage | $I_C = -1\text{mA}, I_B = 0$               | - 300 |      |       | V             |
| $BV_{EBO}$    | Emitter-Base Breakdown Voltage       | $I_E = -10\mu\text{A}, I_C = 0$            | - 5   |      |       | V             |
| $I_{CBO}$     | Collector Cut-off Current            | $V_{CB} = -200\text{V}, I_E = 0$           |       |      | - 0.1 | $\mu\text{A}$ |
| $I_{EBO}$     | Emitter Cut-off Current              | $V_{EB} = -4\text{V}, I_C = 0$             |       |      | - 0.1 | $\mu\text{A}$ |
| $h_{FE}$      | DC Current Gain                      | $V_{CE} = -10\text{V}, I_C = -10\text{mA}$ | 40    |      | 320   |               |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = -20\text{mA}, I_B = -2\text{mA}$    |       |      | - 0.6 | V             |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage      | $I_C = -20\text{mA}, I_B = -2\text{mA}$    |       |      | - 1   | V             |
| $f_T$         | Current Gain Bandwidth Product       | $V_{CE} = -30\text{V}, I_C = -10\text{mA}$ |       | 150  |       | MHz           |
| $C_{ob}$      | Output Capacitance                   | $V_{CB} = -30\text{V}, f = 1\text{MHz}$    |       | 3.1  |       | pF            |
| $C_{re}$      | Reverse Transfer Capacitance         | $V_{CB} = -30\text{V}, f = 1\text{MHz}$    |       | 2.3  |       | pF            |

\* Pulse Test: Pulse Width $\leq$ 300 $\mu\text{s}$ , Duty Cycles $\leq$ 2%**Ordering Information**

| Part Number* | Marking  | Package | Packing Method | Remarks      |
|--------------|----------|---------|----------------|--------------|
| 2SA1381CSTU  | 2SA1381C | TO-126  | TUBE           | hFE1 C grade |
| 2SA1381DSTU  | 2SA1381D | TO-126  | TUBE           | hFE1 D grade |
| 2SA1381ESTU  | 2SA1381E | TO-126  | TUBE           | hFE1 E grade |
| 2SA1381FSTU  | 2SA1381F | TO-126  | TUBE           | hFE1 F grade |
| KSA1381CSTU  | A1381C   | TO-126  | TUBE           | hFE1 C grade |
| KSA1381DSTU  | A1381D   | TO-126  | TUBE           | hFE1 D grade |
| KSA1381ESTU  | A1381E   | TO-126  | TUBE           | hFE1 E grade |
| KSA1381FSTU  | A1381F   | TO-126  | TUBE           | hFE1 F grade |

- \* 1. Affix "-S-" means the standard TO126 Package.(see package dimensions). If the affix is "-STS-" instead of "-S-", that mean the short-lead TO126 package.  
 2. Suffix "-TU" means the tube packing. The Suffix "TU" could be replaced to other suffix character as packing method.

# Typical Characteristics

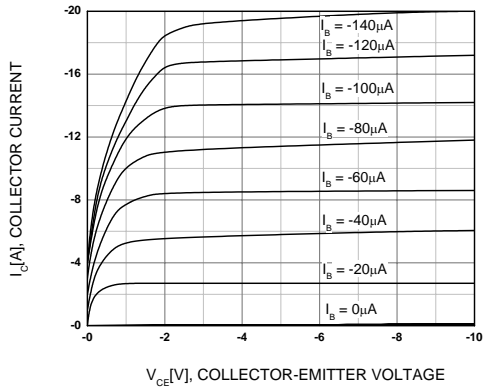


Figure 1. Static Characteristic

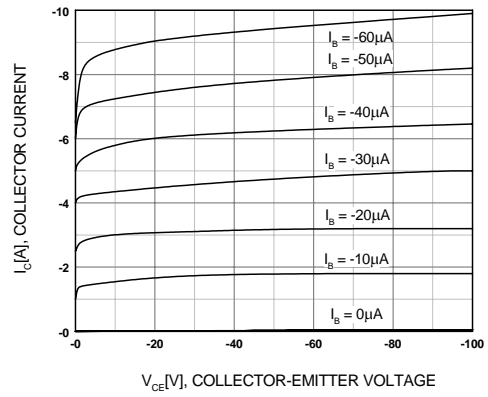


Figure 2. Static Characteristic

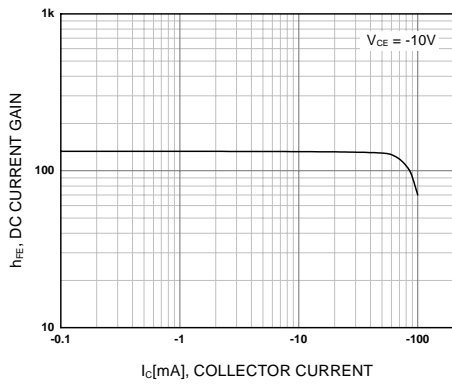


Figure 3. DC current Gain

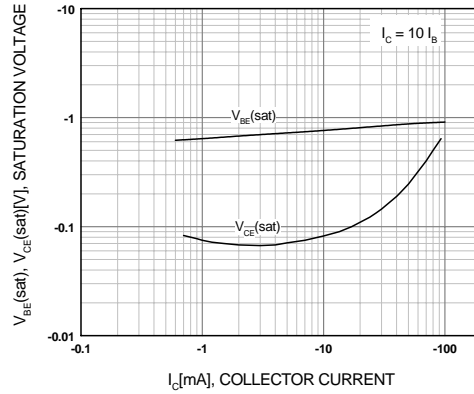


Figure 4. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

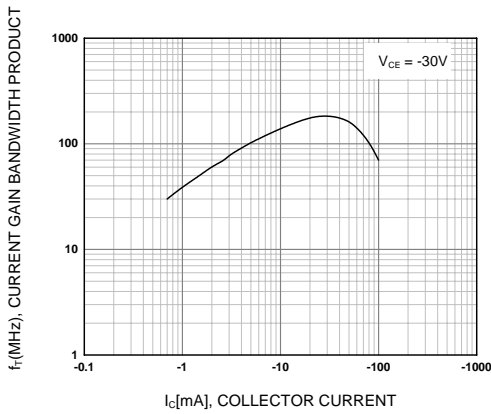


Figure 5. Current Gain Bandwidth Product

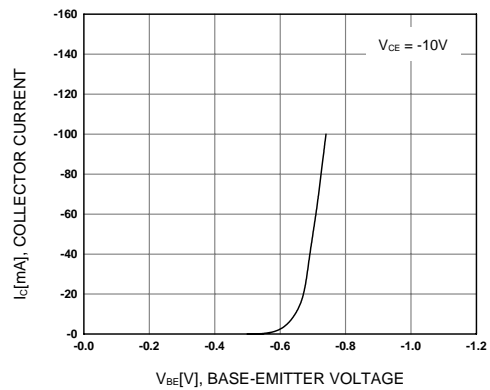


Figure 6. Base-Emitter On Voltage

Typical Characteristics (Continued)

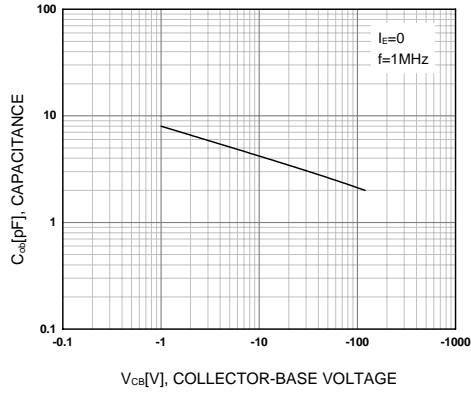


Figure 7. Collector Output Capacitance

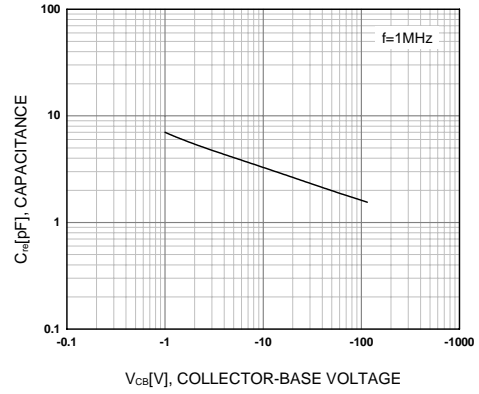


Figure 8. Reverse Transfer Capacitance

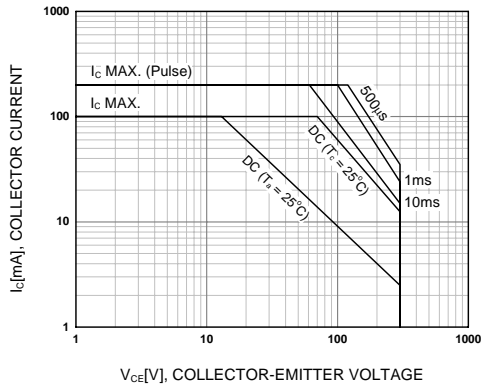


Figure 9. Safe Operating Area

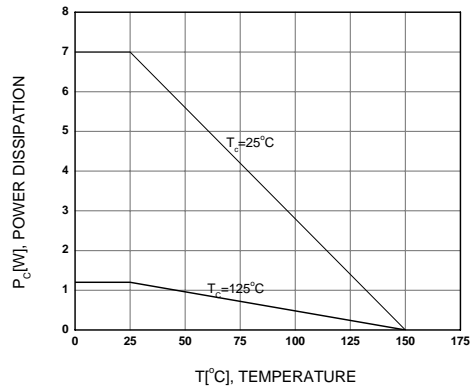
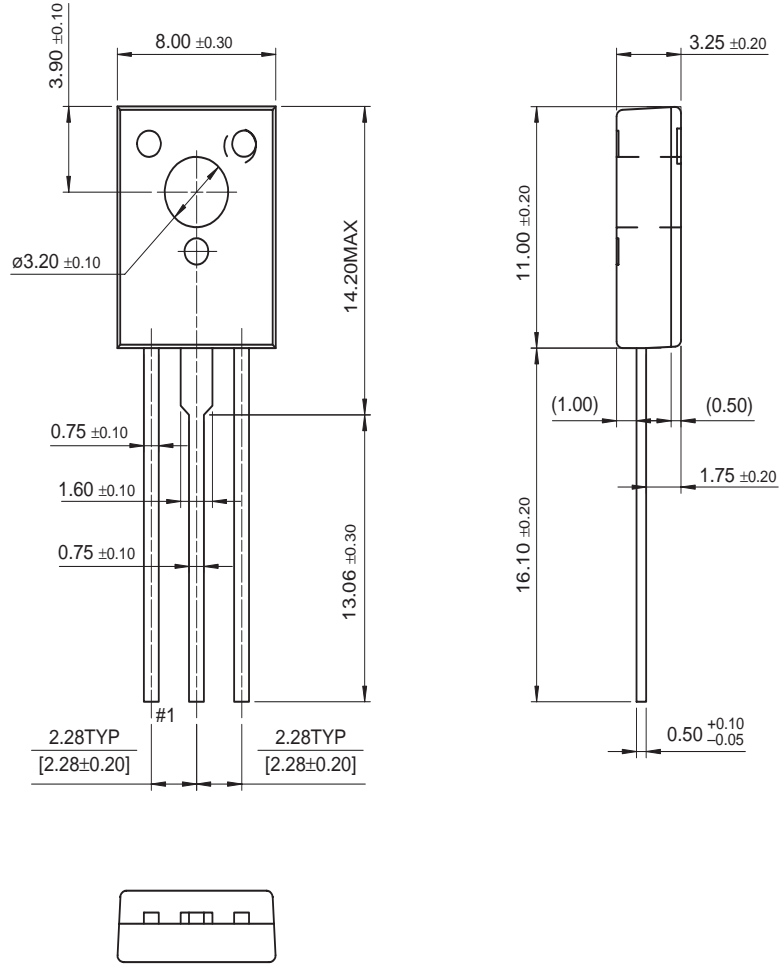


Figure 10. Power Derating

# Package Dimensions

## TO-126



Dimensions in Millimeters



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| CROSSVOLT™  | i-Lo™   | PowerTrench®               |  |
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| EcoSPARK®   | MegaBuck™   | QS™                        | TinyLogic®  |
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